NPN Epitaxial Planar Silicon Transistor



2SC4855

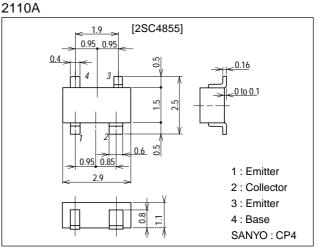
Low-Voltage, Low-Current& High-Frequency Amplifier Applications

Features

 $\cdot \text{ Low-voltage, low-current operation : } f_T=5GHz \text{ typ.} \\ (V_{CE}=1V, I_C=1mA) : |S21e|^2=7.5dB \text{ typ} \\ (f=1GHz). \\ : NF=2.6dB \text{ typ (}f=1GHz).$

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		12	V
Collector-to-Emitter Voltage	VCEO		6	V
Emitter-to-Base Voltage	VEBO		1.5	V
Collector Current	IC		15	mA
Collector Dissipation	PC		80	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
Falanielei		Conditions	min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =5V, I _E =0			1.0	μA
Emitter Cutoff Current	IEBO	V _{EB} =1V, I _C =0			10	μA
DC Current Gain	hFE	V _{CE} =1V, I _C =1mA	60*		270*	
Gain-Bandwidth Product	fT	V _{CE} =1V, I _C =1mA		5		GHz
Output Capacitance	Cob	V _{CB} =1V, f=1MHz		0.6	1.0	pF

 \ast : The 2SC4855 is classified by 1mA h_{FE} as follows :

60 3 120 90 4 180 135 5 270

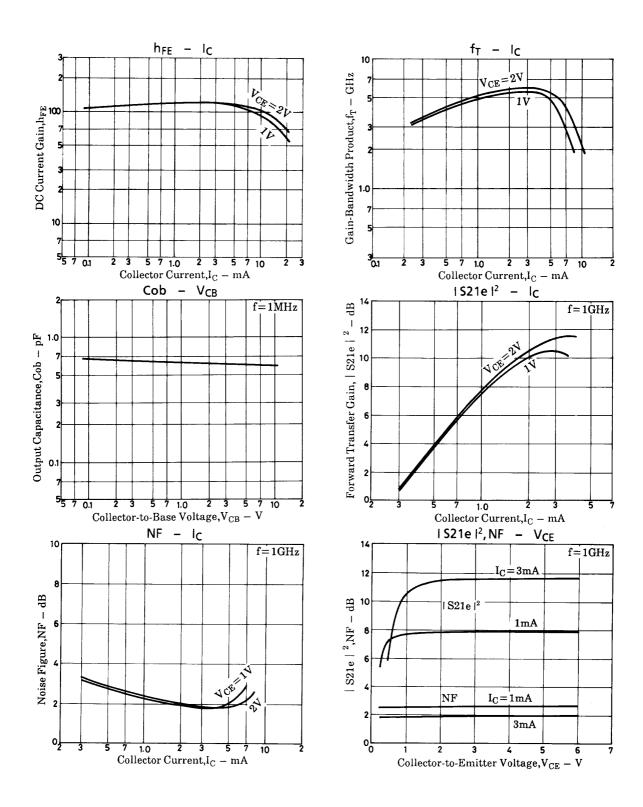
Marking : CN

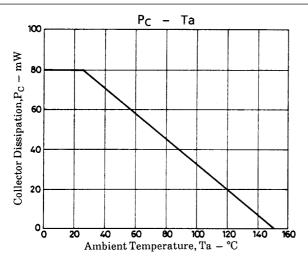
 $h_{FE}\ rank: 3,\,4,\,5$

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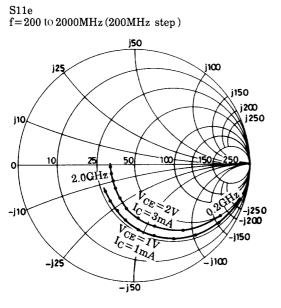
Parameter	Symbol	Conditions		Ratings		
i didificici	Gymbol			typ	max	Unit
Forward Transfer Gain	S21e ² 1	V _{CE} =1V, I _C =1mA, f=1GHz	5	7.5		dB
	S21e ² 2	V _{CE} =2V, I _C =3mA, f=1GHz		11.5		dB
Noise Figure	NF1	V _{CE} =1V, I _C =1mA, f=1GHz		2.6	4.5	dB
	NF2	V _{CE} =2V, I _C =3mA, f=1GHz		1.9		dB

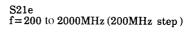


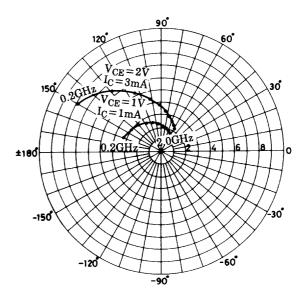


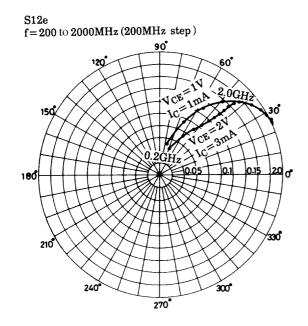
S parameter



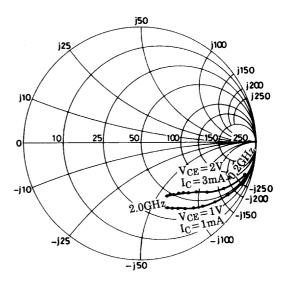








 $\begin{array}{l} S22e \\ f \!=\! 200 \mbox{ to } 2000 MHz \, (200 MHz \mbox{ step }) \end{array}$



S parameter (Common emitter)

 $V_{CE}=1V$, $I_C=1mA$, $Z_O=50\Omega$

Freq (MHz)	S ₁₁	∠ S ₁₁	S ₂₁	∠ S ₂₁	S ₁₂	∠ S ₁₂	S ₂₂	∠ S ₂₂
200	0.944	-18.0	3.276	159.9	0.050	76.8	0.981	-12.0
400	0.869	-34.2	3.037	143.8	0.093	65.5	0.928	-22.2
600	0.786	-48.9	2.778	130.2	0.128	56.5	0.865	-31.1
800	0.706	-62.0	2.550	117.6	0.155	48.8	0.808	-38.6
1000	0.619	-75.4	2.379	106.1	0.173	42.3	0.753	-45.7
1200	0.547	-87.4	2.165	95.7	0.186	36.9	0.712	-51.2
1400	0.473	-100.1	2.022	85.9	0.194	32.4	0.675	-56.1
1600	0.417	-111.7	1.840	77.4	0.198	28.9	0.639	-60.4
1800	0.371	-125.2	1.745	69.9	0.202	26.4	0.614	-64.1
2000	0.343	-139.3	1.639	62.2	0.201	25.2	0.595	-67.6

$V_{CE}=2V$, $I_C=3mA$, $Z_O=50\Omega$

Freq (MHz)	S ₁₁	∠ s ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠ s ₁₂	S ₂₂	∠ S ₂₂
200	0.844	-30.5	7.785	149.6	0.043	71.0	0.933	-17.4
400	0.688	-53.7	6.308	129.2	0.072	59.3	0.808	-28.8
600	0.545	-72.1	5.182	113.8	0.091	52.6	0.705	-36.3
800	0.451	-86.7	4.315	102.3	0.104	49.2	0.632	-41.6
1000	0.374	-102.0	3.713	95.2	0.117	47.0	0.590	-46.0
1200	0.308	-115.4	3.225	83.5	0.127	45.9	0.564	-49.5
1400	0.260	-130.6	2.823	75.5	0.137	45.0	0.541	-53.1
1600	0.230	-145.2	2.515	68.8	0.146	44.5	0.525	-56.8
1800	0.215	-160.5	2.296	63.0	0.155	44.2	0.510	-60.3
2000	0.213	-177.0	2.143	56.9	0.166	43.8	0.506	-63.4

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